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Charge and spin transport across graphene and multifunctional oxide interfaces

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Charge and spin transport across graphene and multifunctional oxide interfaces

Towards energy-efficient logic and memory devices



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university of
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Charge and spin transport across graphene and multifunctional oxide interfaces

Towards energy-efficient logic and memory devices

PhD thesis

to obtain the degree of PhD at the
 University of Groningen
 on the authority of the
 Rector Magnificus Prof. C. Wijmenga
 and in accordance with
 the decision by the College of Deans.

This thesis will be defended in public on

Tuesday 5 April 2022 at 11:00 hours

by

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to my parents, grandparents, and Wytse

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